

Ultrafast Rectifier, 2 A FRED Pt®



SMB (DO-214AA)

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)} 2 A						
V _R	200 V					
V _F at I _F	0.66 V					
t _{rr} typ.	24 ns					
T _J max.	175 °C					
Package	SMB (DO-214AA)					
Circuit configuration	Single					

FEATURES

- Ultrafast recovery time, reduced Q_{rr} and soft recovery
- 175 °C maximum operating junction temperature
- Specific for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, ultrafast recovery time, and fast recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in snubber, output operation, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element.

MECHANICAL DATA

Case: SMB (DO-214AA)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

Polarity: color band denotes the cathode end

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		200	V		
Average rectified forward current	I _{F(AV)}	$T_L = 150 \ ^{\circ}C \ ^{(1)}$	2	А		
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \ ^{\circ}C$, 6 ms square pulse	70	~		
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C		

Note

⁽¹⁾ Mounted on PCB with 6 mm x 3.5 mm lands

ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	200	-	-		
Ferryard valtage	N/	I _F = 2 A	-	0.84	0.9	V	
Forward voltage	V _F	I _F = 2 A, T _J = 150 °C	-	0.66	0.7		
Poweree lookage ourrent		$V_{R} = V_{R}$ rated	-	-	2		
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	20	μA	
Junction capacitance	CT	V _R = 200 V	-	12	-	pF	
Critical rate if rise of reverse voltage	dV/dt_{τ}		-	-	10 000	V/µs	

Revision: 17-Mar-2021

1

Document Number: 96444

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

RoHS COMPLIANT HALOGEN

FREE



DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
			00 A/µs, V _R = 30 V	-	24	-		
		I _F = 1.0 A, dI _F /dt = 50 A/µs, V _R = 30 V		-	27	-		
Reverse recovery time t _{rr}	t _{rr}	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		-	-	23	ns	
	T _J = 25 °C		-	21	-			
		T _J = 125 °C		-	26	-		
Peak recovery current		T _J = 25 °C	$I_{\rm F} = 2 {\rm A}$	-	2.7	-	Α	
Peak recovery current I _{RRM}	T _J = 125 °C	dl _F /dt = 200 A/µs V _B = 100 V	-	3.4	-	A		
Deverse we example the week	0	T _J = 25 °C		-	28	-	nC	
neverse recovery charge	everse recovery charge Q _{rr}			-	43	-	nu	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to mount	R _{thJM} ⁽¹⁾		-	-	17	°C/W
Thermal resistance, junction to ambient	R _{thJA} ⁽¹⁾		-	-	80	0/10
Approximate Weight				0.1		g
Approximate Weight				0.003		oz.
Marking device		Case style SMB (DO-214AA)	2H2			

Note

⁽¹⁾ Units mounted on PCB 6 mm x 3.5 mm land areas

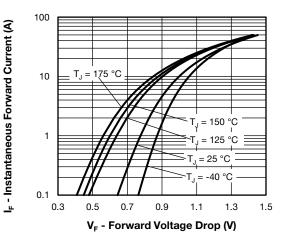


Fig. 1 - Typical Forward Voltage Drop Characteristics

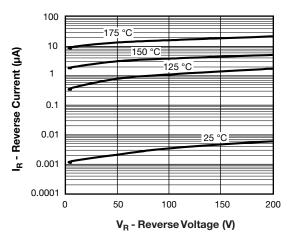
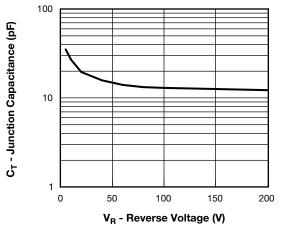


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





www.vishay.com

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

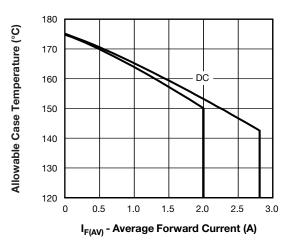


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

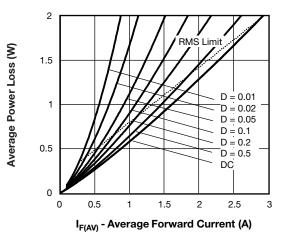
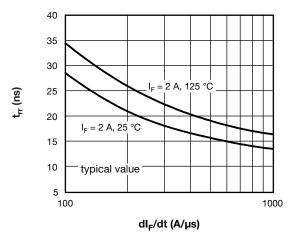
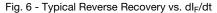


Fig. 5 - Forward Power Loss Characteristics





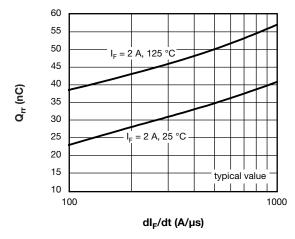
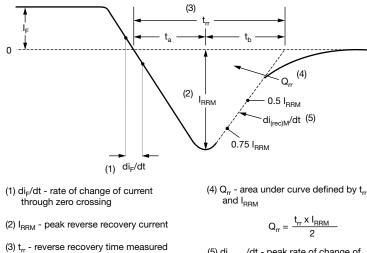


Fig. 7 - Typical Stored Charge vs. dl_F/dt

Revision: 17-Mar-2021 3 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

Document Number: 96444





(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current. (5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

SHAY

www.vishay.com

Device code	VS-	2	Е	G	н	02	-M3
	(1)	(2)	(3)	(4)	(5)	6	(7)
	1	- Visl	nay Sen	niconduo	ctors pro	oduct	
	2	- Cur	rent rati	ng (2 = 2	2 A)		
	3	- Circ	cuit conf	iguratior	ו:		
		E =	single c	liode			
	4	- G =	SMB pa	ackage			
	5	- Pro	cess typ	e,			
	_	H = hyperfast recovery					
	6		•	le (02 =	,		
	7	M3	= halog	gen-free	, RoHS-	complia	ant, and

ORDERING INFORMATION (Example)							
PREFERRED P/N	EFERRED P/N PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-2EGH02-M3/5BT	5BT	3200	13"diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95401					
Part marking information	www.vishay.com/doc?95472				
Packaging information	www.vishay.com/doc?95404				
SPICE model	www.vishay.com/doc?96021				

Revision: 17-Mar-2021

4

Document Number: 96444

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

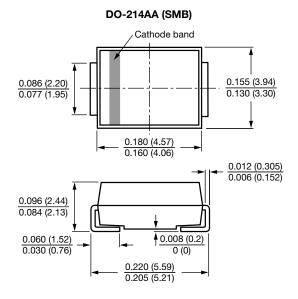


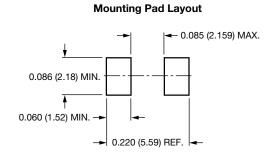
Outline Dimensions

Vishay Semiconductors

SMB

DIMENSIONS in inches (millimeters)







Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2025 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jan-2025

1